Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-824-5178

Inclosure Material:

Metal

Overall Length:

0.505 inches

Overall Diameter:

0.562 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1000.0 reverse voltage, peak

Current Rating Per Characteristic:

25.00 amperes forward current, average of standard range

Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector outside diameter

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Terminal q type 1 and 2; junction pattern arrangement: pnpn

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0